

N-channel TrenchMOS logic level FET

Rev. 02 — 6 May 2009

Product data sheet

1. Product profile

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- AEC-Q101 compliant
- Low conduction losses due to low on-state resistance
- Suitable for logic level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

Motors, lamps and solenoids

1.3 Applications

- 12 V, 24 V and 42 V loads
- Automotive and general purpose power switching

1.4 Quick reference data

Table 1. Quick reference

| | Quicit reference | | | | | |
|----------------------|--|--|-----|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | - | 100 | V |
| I _D | drain current | V _{GS} = 5 V; T _{mb} = 25 °C; see <u>Figure 1</u> ; see <u>Figure 3</u> | - | - | 63 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | - | - | 203 | W |
| Static ch | naracteristics | | | | | |
| R _{DSon} | drain-source on-state resistance | $\label{eq:VGS} \begin{array}{l} V_{GS} = 4.5 \text{ V}; \text{ I}_{D} = 25 \text{ A}; \\ T_{j} = 25 \ ^{\circ}\text{C}; \text{ see } \overline{Figure \ 11}; \\ \text{see } \overline{Figure \ 12} \end{array}$ | - | 16.4 | 22.3 | mΩ |
| | | $V_{GS} = 5 \text{ V}; I_D = 25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ see } Figure 12;$ see Figure 11 | - | 16.2 | 20 | mΩ |
| Avalanc | he ruggedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | $\begin{split} I_D &= 63 \text{ A}; \text{V}_{\text{sup}} \leq 100 \text{ V}; \\ R_{\text{GS}} &= 50 \Omega; \text{V}_{\text{GS}} = 5 \text{V}; \\ T_{j(\text{init})} &= 25 ^\circ\text{C}; \text{ unclamped} \end{split}$ | - | - | 222 | mJ |

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2. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | G | gate | | _ |
| 2 | D | drain | mb | |
| 3 | S | source | | |
| mb | D | mounting base; connected to drain | (D2PAK) | mbb076 S |

3. Ordering information

Table 3.Ordering information

| Type number | Package | | |
|--------------|---------|--|---------|
| | Name | Description | Version |
| BUK9620-100B | D2PAK | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404 |

4. Limiting values

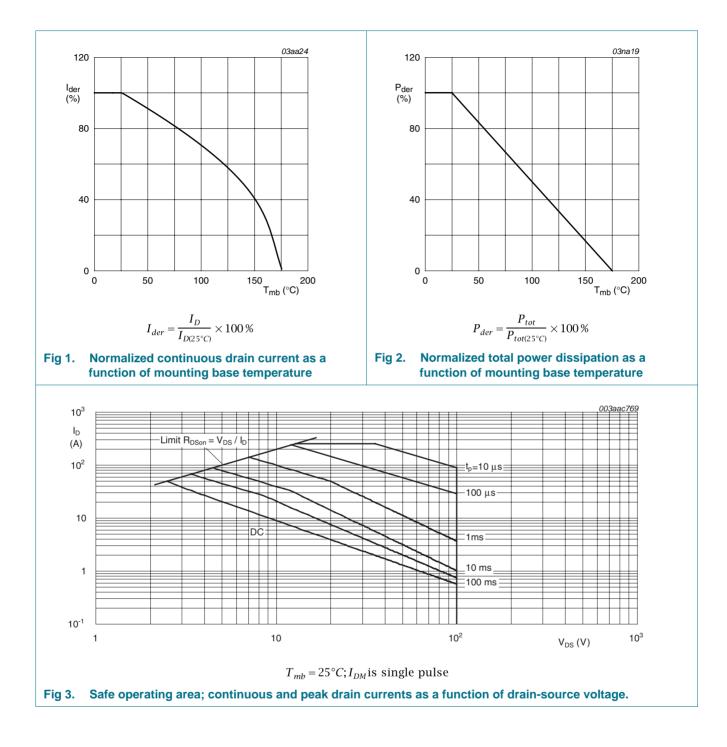
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|--|---|-----|-----|------|
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | 100 | V |
| V _{DGR} | drain-gate voltage | R_{GS} = 20 k Ω | - | 100 | V |
| V _{GS} | gate-source voltage | | -15 | 15 | V |
| I _D | drain current | $T_{mb} = 25 \text{ °C}; V_{GS} = 5 \text{ V}; \text{ see } Figure 1; \text{ see } Figure 3$ | - | 63 | А |
| | | T_{mb} = 100 °C; V_{GS} = 5 V; see <u>Figure 1</u> | - | 45 | А |
| I _{DM} | peak drain current | $T_{mb} = 25 \text{ °C}; t_p \le 10 \mu\text{s}; \text{ pulsed}; \text{ see } \frac{\text{Figure 3}}{10 \mu\text{s}}$ | - | 253 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; see <u>Figure 2</u> | - | 203 | W |
| T _{stg} | storage temperature | | -55 | 175 | °C |
| Tj | junction temperature | | -55 | 175 | °C |
| Source-dr | ain diode | | | | |
| I _S | source current | T _{mb} = 25 °C | - | 63 | А |
| I _{SM} | peak source current | $t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$ | - | 253 | А |
| Avalanche | e ruggedness | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | $ I_D = 63 \text{ A}; \text{V}_{\text{sup}} \leq 100 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \text{V}_{\text{GS}} = 5 \text{ V}; \\ T_{j(\text{init})} = 25 ^{\circ}\text{C}; \text{ unclamped} $ | - | 222 | mJ |

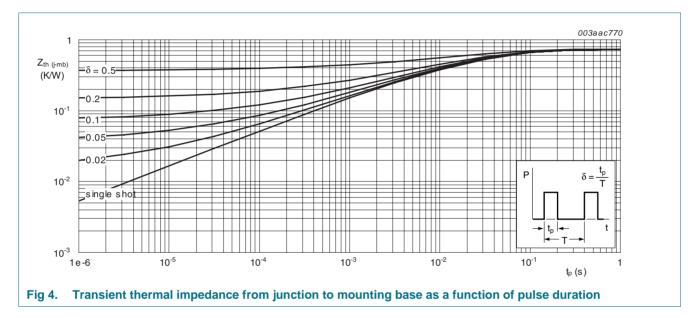
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5. Thermal characteristics

| Table 5. | Thermal characteristics | 5 | | | | |
|-----------------------|---|--|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | see Figure 4 | - | - | 0.75 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | mounted on printed circuit board; minimum footprint; SOT404 package | - | 50 | - | K/W |



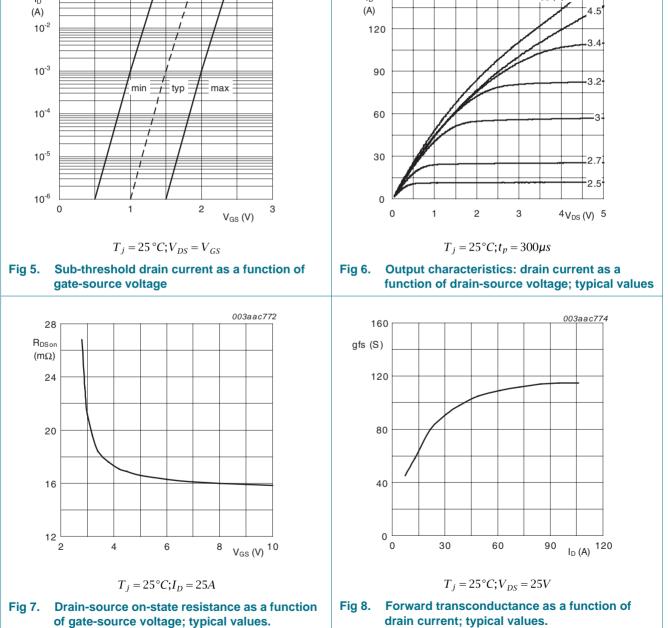
6. Characteristics

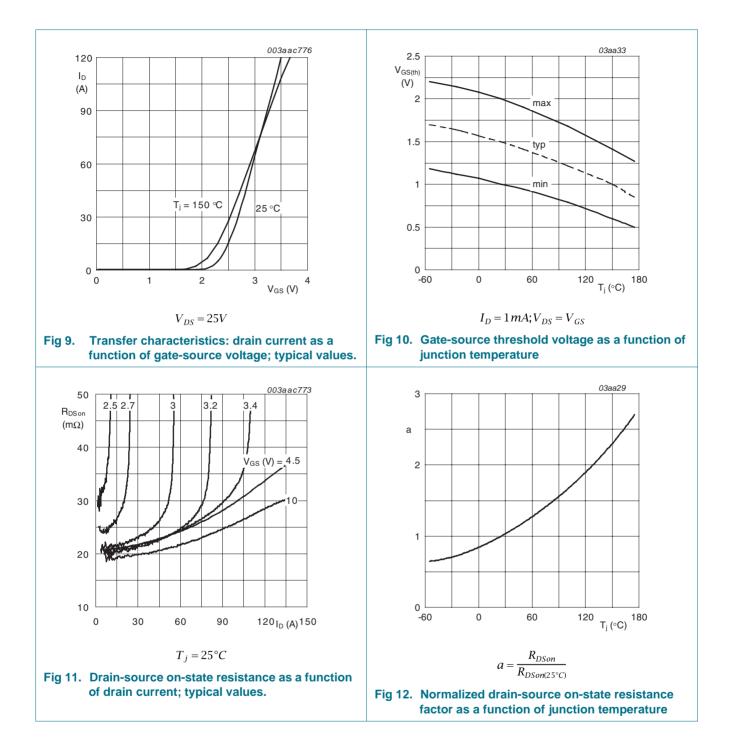
| Table 6. | Characteristics | | | | | |
|---|----------------------------------|---|-----|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | racteristics | | | | | |
| V _{(BR)DSS} | drain-source | I_D = 0.25 mA; V_{GS} = 0 V; T_j = 25 °C | 100 | - | - | V |
| | breakdown voltage | I_D = 0.25 mA; V_{GS} = 0 V; T_j = -55 °C | 90 | - | - | V |
| V _{GS(th)} gate-source thre voltage | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 10</u> | 1 | 1.58 | 2 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 10</u> | 0.5 | - | - | V |
| | | I _D = 1 mA; V _{DS} = V _{GS} ; T _j = -55 °C; see <u>Figure 10</u> | - | - | 2.3 | V |
| I _{DSS} | drain leakage current | V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C | - | - | 500 | μΑ |
| | | $V_{DS} = 100 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | 0.05 | 1 | μA |
| I _{GSS} | gate leakage current | $V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | 2 | 100 | nA |
| | | $V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nA |
| R _{DSon} drain-source on-state resistance | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ see <u>Figure 11</u> ; see <u>Figure 12</u> | - | 16.4 | 22.3 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; see <u>Figure 11</u> ; see <u>Figure 12</u> | - | 15.6 | 18.5 | mΩ |
| | | V _{GS} = 5 V; I _D = 25 A; T _j = 175 °C; see <u>Figure 12</u> ; see <u>Figure 11</u> | - | - | 50 | mΩ |
| | | $V_{GS} = 5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C};$ see <u>Figure 12</u> ; see <u>Figure 11</u> | - | 16.2 | 20 | mΩ |
| Dynamic | characteristics | | | | | |
| Q _{G(tot)} | total gate charge | $I_D = 25 \text{ A}; V_{DS} = 80 \text{ V}; V_{GS} = 5 \text{ V};$ | - | 53.4 | - | nC |
| Q _{GS} | gate-source charge | $T_j = 25 \text{ °C}; \text{ see } Figure 14; \text{ see } Figure 15$ | - | 9.5 | - | nC |
| Q_{GD} | gate-drain charge | | - | 21.2 | - | nC |
| C _{iss} | input capacitance | $V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;$ | - | 4300 | 5657 | pF |
| C _{oss} | output capacitance | $T_j = 25 \text{ °C}; \text{ see } Figure 16$ | - | 340 | 411 | pF |
| C _{rss} | reverse transfer capacitance | | - | 150 | 201 | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 30 \text{ V}; \text{ R}_{L} = 1.2 \Omega; \text{ V}_{GS} = 5 \text{ V};$ | - | 45 | - | ns |
| t _r | rise time | $R_{G(ext)} = 10 \ \Omega; \ T_j = 25 \ ^{\circ}C$ | - | 116 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 173 | - | ns |
| t _f | fall time | | - | 77 | - | ns |
| L _D | internal drain inductance | from drain lead 6 mm from package to centre of die; $T_j = 25 \text{ °C}$ | - | 4.5 | - | nH |
| | | from upper edge of drain mounting base to centre of die; $T_j = 25 \text{ °C}$ | - | 2.5 | - | nH |
| L _S | internal source inductance | from source lead to source bond pad; $T_j = 25 \text{ °C}$ | - | 7.5 | - | nH |

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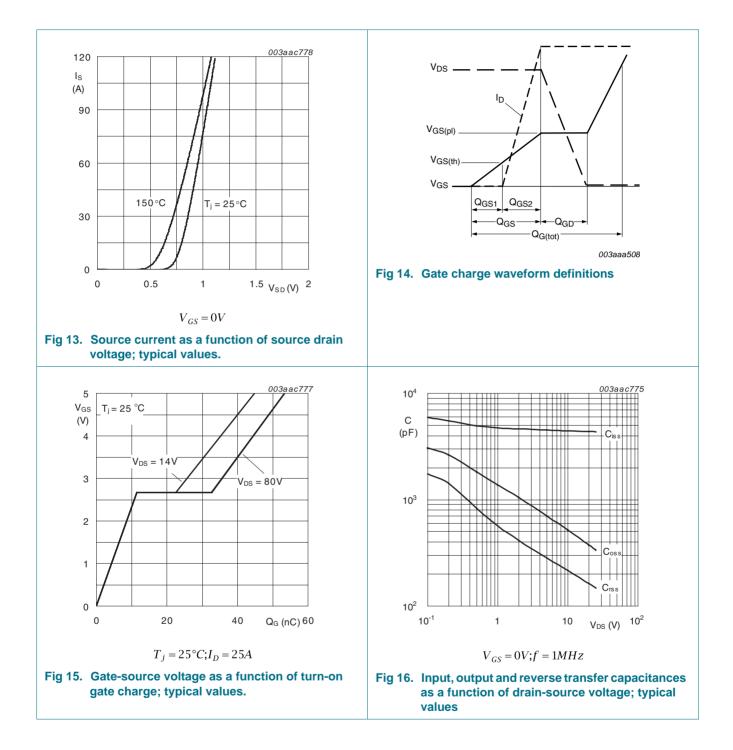
| Table 6. | Characteristics continued | | | | | | |
|---|---------------------------|---|--|---|--------------------|---------------------------|------|
| Symbol | Parameter | Conditions | Conditions | | | Max | Unit |
| Source-d | Irain diode | | | | | | |
| V _{SD} | source-drain voltage | $I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j$ see <u>Figure 13</u> | = 25 °C; | - | 0.86 | 1.2 | V |
| t _{rr} | reverse recovery time | | $I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$ | | 80 | - | ns |
| Qr | recovered charge | V _{DS} = 30 V; T _j = 25 °C | | - | 272 | - | nC |
| 10 ⁻¹ I _D (A) 10 ⁻² | | 03aa36 | 150 I _D (A) 120 | | V _{GS} (\ | 003aac77 () =10 4.5 | |





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7. Package outline

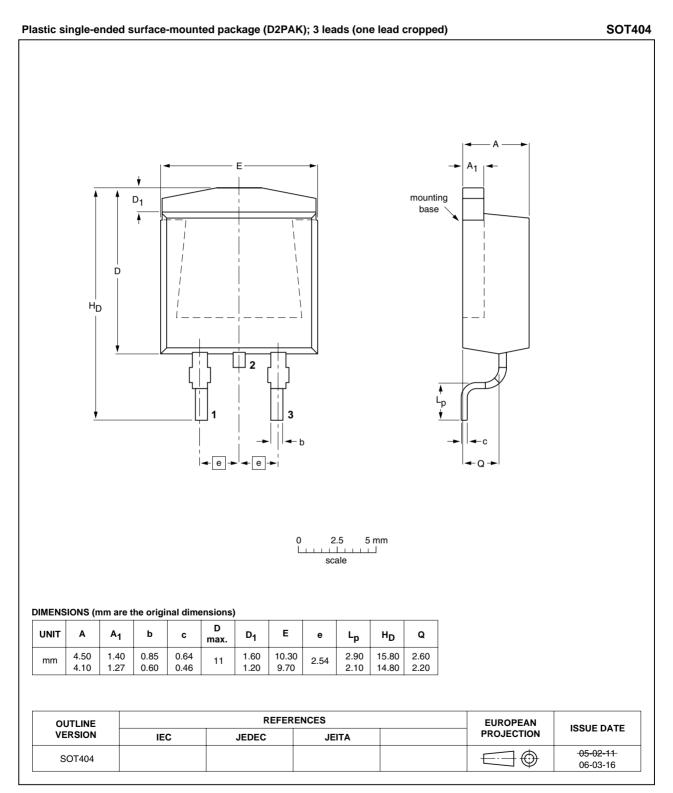


Fig 17. Package outline SOT404 (D2PAK)

8. Revision history

| Table 7. | Revision | history |
|----------|----------|---------|
|----------|----------|---------|

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|-------------------------------|----------------------------|------------------------|----------------|
| BUK9620-100B_2 | 20090506 | Product data sheet | - | BUK9620-100B_1 |
| Modifications: | Data shee | et status changed from 'Ob | jective' to 'Product'. | |
| BUK9620-100B_1 | 20090323 | Objective data sheet | - | • |

9. Legal information

9.1 Data sheet status

| Document status [1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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